MSKSEMI 美森科













ESD

TSS

MOV

GDT

PIFD

K22-MS THRU K210-MS

Product specification





FEATURES

- Ideal for surface mount applications
- Easy pick and place
- Built-in strain relief
- Low forward voltage drop

MECHANICAL DATA

Case: Molded plastic

• Epoxy: UL 94V-0 rate flame retardant

Metallurgically bonded construction

Polarity: Color band denotes cathode end

Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25° C ambient temperature unless otherwies specified . Single phase half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

TYPE NUMBER	K22-MS	K23-MS	K24-MS	K25-MS	K26-MS	K28-MS	K29-MS	K210-MS	UNITS
Maximum Recurrent Peak Reverse Voltage	20	30	40	50	60	80	90	100	V
Maximum RMS Voltage	14	21	28	35	42	56	63	70	V
Maximum DC Blocking Voltage	20	30	40	50	60	80	90	100	V
Maximum Average Forward Rectified Current		1			1			1	
See Fig. 1	2.0				Α				
Peak Forward Surge Current, 8.3 ms single half									
sine-wave superimposed on rated load (JEDEC	50					Α			
method)									
Maximum Instantaneous Forward Voltage at 2.0A	0.55		0.70		0.85		V		
Maximum DC Reverse Current	0.1 0.02					mA			
at Rated DC Blocking Voltage	5 2					mA			
Typical Junction Capacitance (Note1)	170					pF			
Typical Thermal Resistance R JA (Note 2)	80					C/W			
Operating Temperature Range T _J	-65 —— +150					$^{\circ}$			
Storage Temperature Range TstG	-65 —— +150					$^{\circ}$			
Marking Code									

NOTES:

- 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
- 2. Thermal Resistance Junction to Ambient.



RATINGAND CHARACTERISTIC CURVES (DSK22 THRU DSK210)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

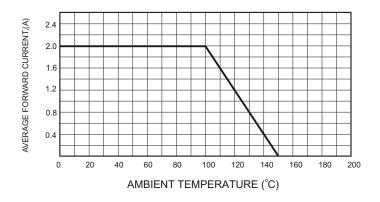


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

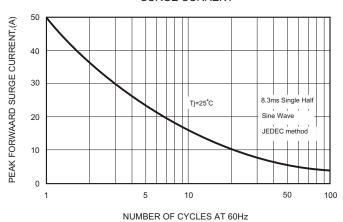


FIG.4-TYPICAL JUNCTION CAPACITANCE

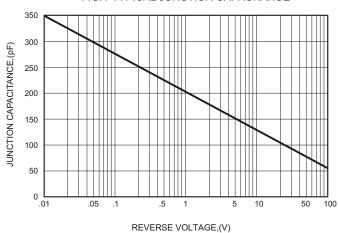


FIG.2-TYPICAL FORWARD

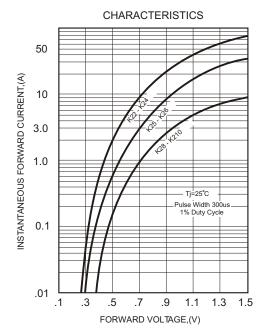
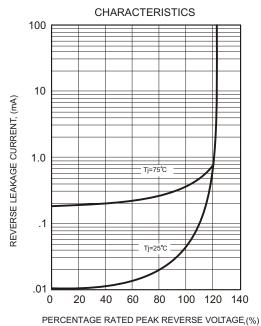
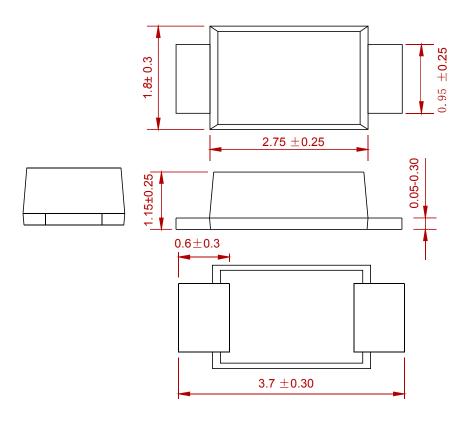


FIG.5 - TYPICAL REVERSE



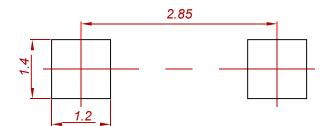


PACKAGE MECHANICAL DATA



Dimensions in millimeters

Suggested Pad Layout



Note:

- 1. Controlling dimension: in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
K22-MS THRU K210-MS	K22-MS THRU K210-MS SOD-123FL	



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